Production Wafer Probe of 77-81 GHz Automotive Radar Applications

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Outline

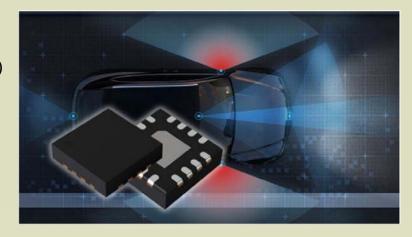
- Introduction Automotive Radar Devices and Testing
- Benefits and Challenges in testing the new generation
- Testing requirements and options
 - Pogo with PCB absorber
 - Membrane Solution
 - xWave with absorber
 - Advantages
 - · Modification to the standard xWave
- Test Results
 - Initial and current
- Improvements along the way
- Next Steps
- Summary/Conclusion



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Introduction

- Automotive Radar has been used since 2007
 - First Generation (Approximately 2007 2013)
 - 28 Ghz
 - · Short range
 - · Limited functionality
 - Second Generation (Approximately 2014 2018)
 - 80 Ghz improved resolution
 - Longer range
 - · Increased functionality
- Now entering a third generation (2019 TBD)
 - 80 Ghz
 - Longest range
 - Increased performance and functionality
 - Lower cost
 - New testing challenges





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Introduction – Cont.

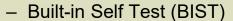
- Second Generation
 - Devices packaged in traditional formats (i.e. BGA, QFN, etc.)
 - Multiple packages for receiver (RX), transmitter (TX) and voltage controller (VCO)
 - Packages combined into module
 - Testing required at multiple levels (wafer, film frame, package, transceiver module)
 - About 15 tests, many of them repetitive
 - mmWave Automated Test Equipment (ATE)
 - Expensive new
 - Difficult to get repeatable results due to sensitivity
 - Extensive set-up due to calibration
 - Basically need an RF Lab on your test floor with RF engineers to keep it going!



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Benefits in testing the new generation

- Third Generation
 - Die level integration of receiver (RX), transmitter (TX) and voltage controller (VCO)
 - Packages no longer required
 - Testing required at wafer and WLCSP
 - ambient, hot, cold, fewer total tests and less repetition (4 total)



- BIST allows die to do internal testing.
- Eliminates need for expensive mmWave test equipment
- · Better fit with standard wafer test environment
- Multi Site Testing
 - · Higher throughput

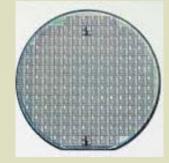




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Challenges in testing the new generation

- Built-in Self Test (BIST)
 - Requires the I/O for the high frequency signals to be properly terminated while still providing a path for sourcing a DC voltage to the DUT.
 - New functionality in the test hardware/probehead
 - Dual frequency ranges to optimize with differing absorption requirements
- Wafer/WLCSP testing
 - Smaller target
 - More sensitive to coplanarity
 - Temperature sensitivity
- Integration of the three devices into one die
 - More complex test program





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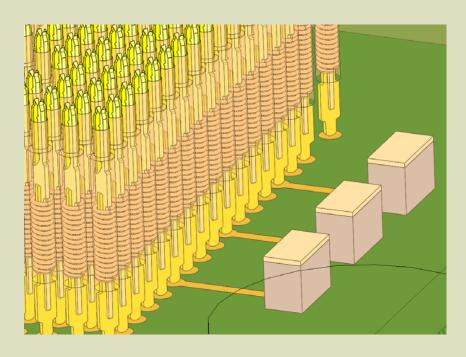
Challenges in testing the new generation (cont.)

- Multi Site Testing
 - Coplanarity challenges
 - · Reduction of forces
 - Adding support for PCB (Bridge Beam)
 - Site to site alignment
 - Site to site variation
 - CTE
- Contact Technology Dual
 - Spring Probes for standard signals
 - Leadframe for RF frequency signals
- Production Worthy Solution



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Test Solutions – Absorber on PCB

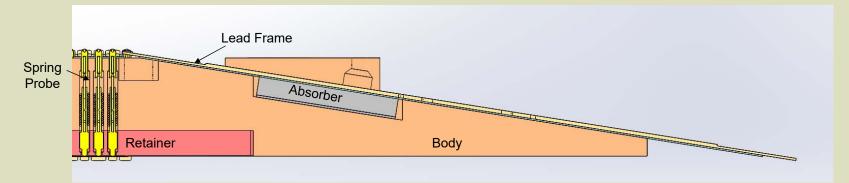


 90° transition at PCB creates significant signal reflection



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Test Solutions – Prototype Build Leadframe with PCB Connection



Issues Solved

- Straight leadframe with shallow angle connection to PCB reduces reflections.
- Absorber attenuates signal.

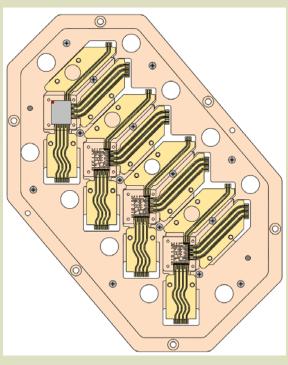
New Issues

- Tolerances of absorber create mechanical bowing issues
- Initial leadframe mechanics require larger than planned overdrive



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Test Solutions – Prototype Build Leadframe with PCB Connection - MultiSite



 Multi-site required some new thinking with leadframes fanning out at 45° from three sides



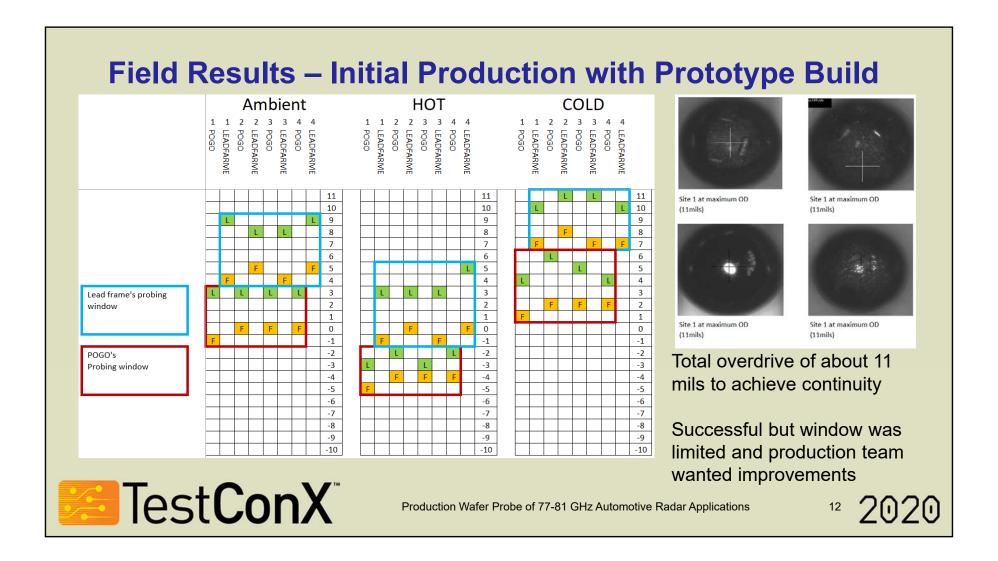
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Challenges in Prototype Build

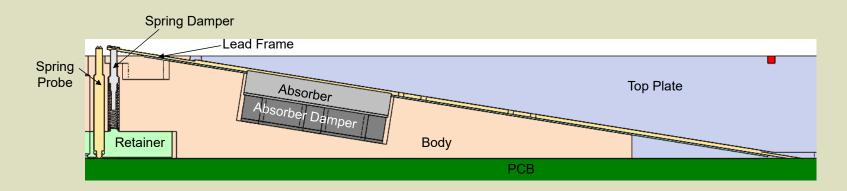
- Bowing of Probehead
 - Additional mounting locations required
 - Reduction of force applied by absorbers more compliant second layer
 - Redesign of components to add rigidity
- Coplanarity of PCB
 - Stiffener in original design
 - Added adjustable support beam to coplanarize
- Logistics Across Multiple Sites
 - Probe Card Stiffener compatibility



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Test Solutions – Production Build

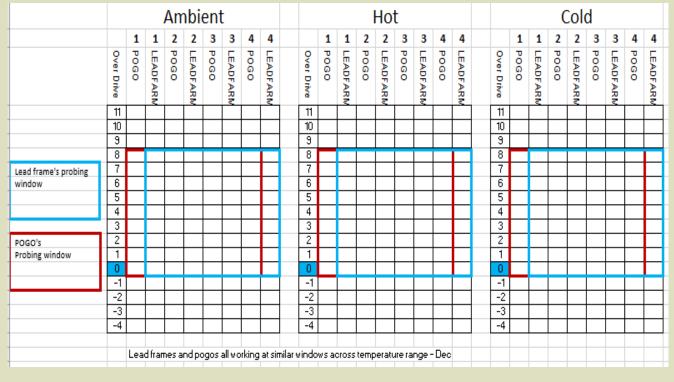


- Spring damper to better support leadframes
- Absorber damper to add compliance/reduce bowing of top plate



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Field Results – Improved Production



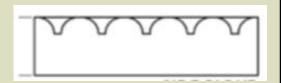
- Full continuity at all temps at 8 mils of overdrive
- Max overdrive of 13 mils allowed
- 5 mil working window
- Production team approved for release



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Field Results – Ongoing concerns

- Over 250,000 insertions on the first probe head
- In-Situ cleaning as angled leadframes are more difficult to clean than pogo pins or flat leadframes – reviewing new cleaning media
- Absorber system may degrade over time and require repair/improvement





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¹⁵ 2020

Strengths

- Excellent RF performance over a broad range of frequencies
- Long life
- Multi-site capability
- Large compliance window



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Weakness

- Complex to balance multiple contact technologies on one DUT
- Some limits on the number and location of RF signals
- In-situ cleaning is difficult
- May need maintenance on absorpbtion system over time



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⁷ 2020

Next Steps

- Project has moved to production and additional test cells are being deployed to meet end user demand!
- Testing in-situ cleaning media and methods
- Testing life performance of absorption system
- Better control of force on leadframes with modifications to support system (future projects)
- Have improved tolerance capabilities and geometries on leadframes
- Have implemented pad compatible geometries



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Summary/Conclusion

- Advances in IC design architectures and contacting methods make high volume test of automotive radar RF devices production capable with test resources already available on production floors.
- Thank you to NXP for the opportunity and collaboration to make it happen!



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Total Solutions - Test Cell Integration & Automated Test Equipment

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